

Wavelength	Type	Technology	Case
UV-B	clear UV-glass + filters	SiC	TO-39

		Description
		Selective photodiode with high spectral sensitivity in the UVB range (290 nm - 330 nm), mounted in hermetically sealed TO-39 package with clear UV-glass window and filters Note: housing with diffuse glass window available on request
Applications		Environmental technology, analytical techniques, medical applications, industrial sensors, inspecting and controlling of UV radiation as well as for more general purposes

Miscellaneous Parameters $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Value	Unit
Active area		A	0.056	mm^2
Temperature coefficient of I_{ph}		$T_C(I_{ph})$	0.1	%/K
Operating temperature range		T_{amb}	-40 to +70	°C
Storage temperature range		T_{stg}	-40 to +100	°C
Acceptance angle at 50% S_λ		ϕ	70	deg.

Optical and Electrical Characteristics $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Min	Typ	Max	Unit
Breakdown voltage ¹⁾	$I_R = 100 \mu\text{A}$	V_R		20		V
Dark current	$V_R = 1 \text{ V}$	I_D		10	100	fA
Peak sensitivity wavelength	$V_R = 0 \text{ V}$	λ_p		310		nm
Responsivity at λ_p	$V_R = 0 \text{ V}$	S_λ		0.013		A/W
Sensitivity range at 1%	$V_R = 0 \text{ V}$	$\lambda_{min}, \lambda_{max}$	290		330	nm
Spectral bandwidth at 50%	$V_R = 0 \text{ V}$	$\Delta\lambda_{0.5}$		26		nm
Shunt resistance	$V_R = 10 \text{ mV}$	R_{SH}		1		TΩ
Noise equivalent power	$\lambda = 310 \text{ nm}$	NEP		1.1×10^{-14}		$\text{W}/\sqrt{\text{Hz}}$
Specific detectivity	$\lambda = 310 \text{ nm}$	D^*		2.2×10^{12}		$\text{cm} \cdot \sqrt{\text{Hz}} \cdot \text{W}^{-1}$
Junction capacitance	$V_R = 0 \text{ V}$	C_J		20		pF
Photo current at $\lambda = 320 \text{ nm}^{1,2)}$	$V_R = 0 \text{ V}$ $E_e = 100 \mu\text{W}/\text{cm}^2$	I_{ph}		0.6		nA

¹⁾for information only²⁾measured with Phillips UV-lamp TL 4W/12

Note: All measurements carried out with EP/GAP equipment

Labeling

Type	Lot N°	R_D (typ.) [TΩ]	Quantity
EPD-310-0-0.3-1			

